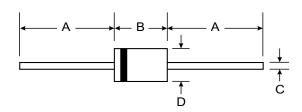


# SF20AG - SF20JG

## 2.0A SUPER-FAST GLASS PASSIVATED RECTIFIER

#### **Features**

- Glass Passivated Die Construction
- Diffused Junction
- Super-Fast Switching for High Efficiency
- High Current Capability and Low Forward Voltage Drop
- Surge Overload Rating to 60A Peak
- Low Reverse Leakage Current
- Plastic Material: UL Flammability Classification Rating 94V-0



### **Mechanical Data**

Case: Molded Plastic

Terminals: Plated Leads Solderable per
Null CTD 200 Mathe d 200

MIL-STD-202, Method 208

Polarity: Cathode Band

Marking: Type NumberWeight: 0.35 grams (approx.)

Mounting Position: Any

DO-15							
Dim	Min	Max					
Α	25.40	_					
В	5.50	7.62					
С	0.686	0.889					
D	2.60	3.6					
All Dimensions in mm							

# Maximum Ratings and Electrical Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	SF20 AG	SF20 BG	SF20 CG	SF20 DG	SF20 FG	SF20 GG	SF20 HG	SF20 JG	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	50	100	150	200	300	400	500	600	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	35	70	105	140	210	280	350	420	V
Average Rectified Output Current @ T <sub>A</sub> = 75° (Note 1)	C Io	2.0						Α		
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave Superimposed on Rated Load (JEDEC Method)		60							А	
Forward Voltage @ I <sub>F</sub> = 2.0	A V <sub>FM</sub>	0.95 1.			.3	1.5		V		
		10 100						μА		
Reverse Recovery Time (Note 2)		35			40		50		ns	
Typical Junction Capacitance (Note 3)		75 50						60	pF	
Typical Thermal Resistance Junction to Ambient		40							K/W	
Operating and Storage Temperature Range		-65 to +150							°C	

Notes:

- 1. Valid provided that leads are kept at ambient temperature at a distance of 9.5mm from the case.
- 2. Measured with  $I_F = 0.5A$ ,  $I_R = 1.0A$ ,  $I_{rr} = 0.25A$ . See Figure 5.
- 3. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

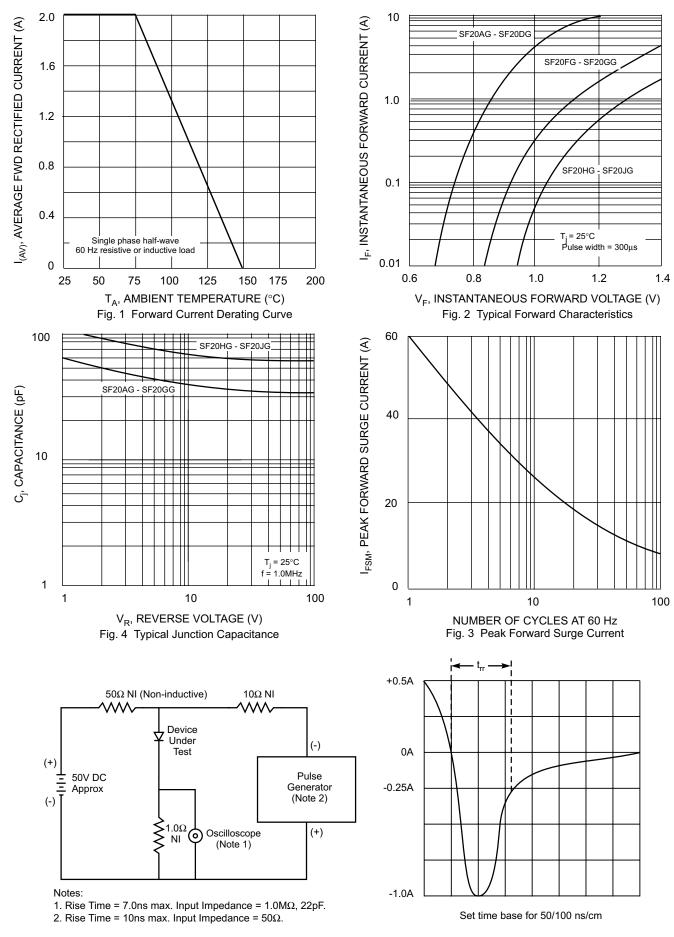


Fig. 5 Reverse Recovery Time Characteristic and Test Circuit